



GP
ELECTRONICS

SS32B-SS320B

20~200V-3A Schottky Rectifier

SS32B-SS320B Schottky Rectifier

Feature

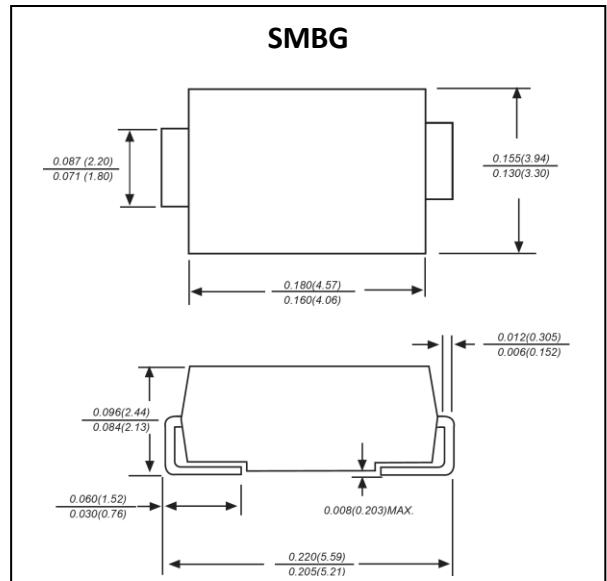
- High current capability
- Low VF
- High surge current capability

Application

- Rectifier

Marking

- SS3X
- X: From 2 To 20



ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	SS3									Unit
		2	3	4	5	6	8	10	15	20	
Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	56	70	105	140	V
Average Forward Current (60HZ Half-sine wave, Resistance load, TL(Fig.1))	$I_{F(AV)}$	3.0									A
Non-repetitive Peak Forward Surge Current (60Hz Half-sine wave ,1 cycle , $T_a=25^\circ\text{C}$)	I_{FSM}	70									A
Junction Temperature	T_J	-55 ~ +125			-55 ~ +150						°C
Storage Temperature	T_{STG}	-55 ~ +150									°C

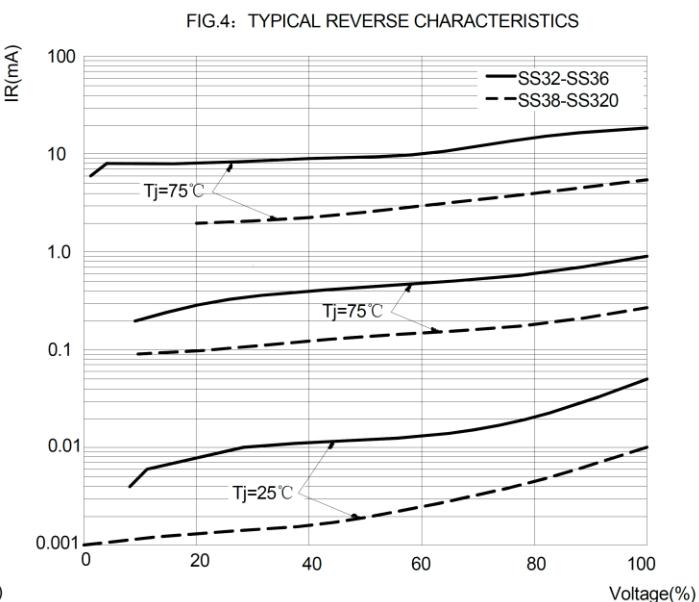
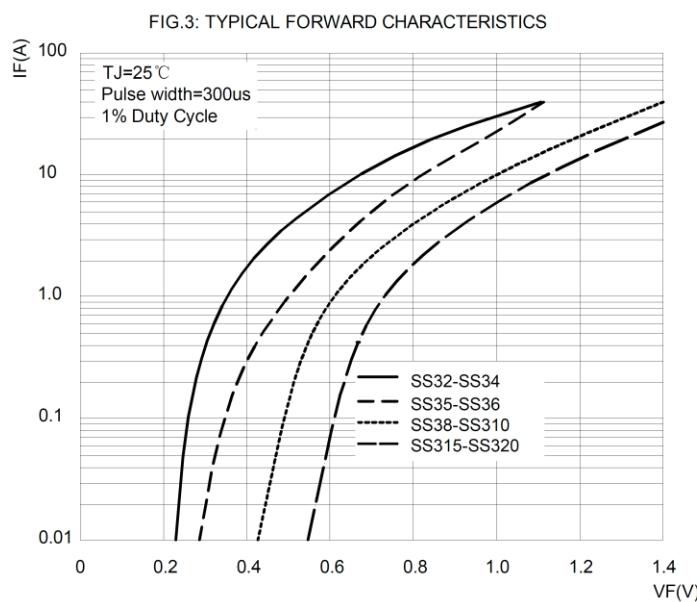
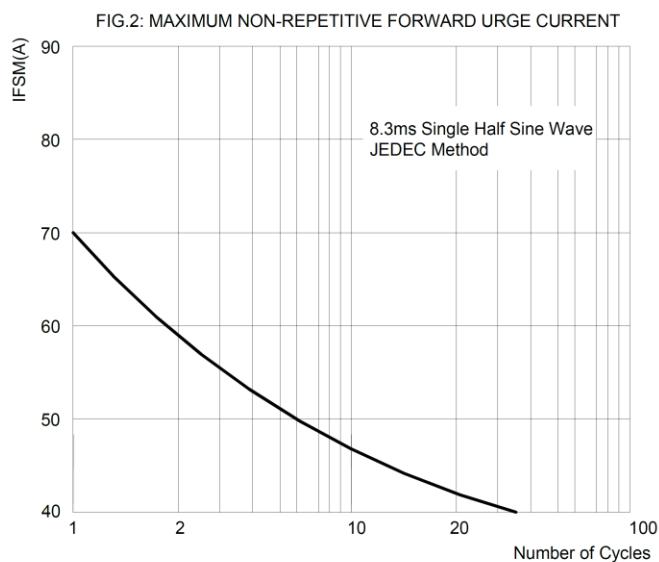
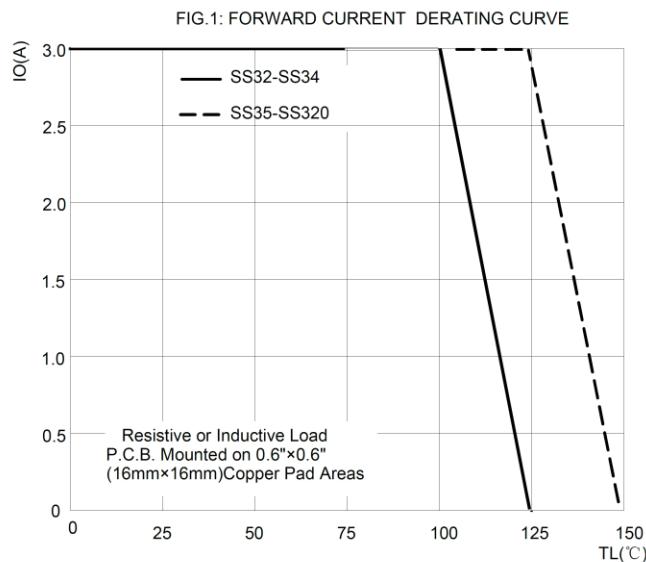
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	SS3								Unit							
			2	3	4	5	6	8	10	15								
Peak Forward Voltage	V_F	$I_F = 1\text{A}$			0.55	0.70		0.85	0.95		V							
Peak Reverse Current	I_{RRM1}	$V_{RM}=V_{RRM}$	$T_a=25^\circ\text{C}$	0.5				0.1										
	I_{RRM2}			$T_a=100^\circ\text{C}$		10	5.0				mA							
Thermal Resistance(Typical)	$R_{\theta J-A}$	Between junction and ambient		55														
	$R_{\theta J-L}$	Between junction and terminal		17														

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.27" x 0.27" (7.0 mm x 7.0 mm) copper pad areas

Typical Characteristics



单击下面可查看定价，库存，交付和生命周期等信息

[>>GP\(格瑞宝\)](#)